NSN 5962-01-171-6840



Memory Microcircuit - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5962-01-171-6840 **Body Length:** Between 0.985 inches and 1.015 inches **Body Width:** Between 0.300 inches and 0.320 inches **Body Height:** Between 0.088 inches and 0.108 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** High performance and static operation and w/enable and 3-state output **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** N-type metal oxide-semiconductor logic **Input Circuit Pattern:** 17 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -0.3 volts power source and 7.0 volts power source **Time Rating Per Chacteristic:** 55.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Rom **Terminal Type And Quantity:** 20 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Yes - demil/mli

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